





20V PNP SILICON LOW SATURATION TRANSISTOR IN SOT23

Features and Benefits

- BV_{CEO} > -20V
- I_C = -1A Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -320mV @ -1A
- h_{FE} characterised up to -1.5A for high current gain hold-up
- 500mW power dissipation
- Complementary part number FMMTL618
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- UL Flammability Rating 94V-0
- Case material: molded Plastic.
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Matte Tin Finish annealed over Copper plated Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (Approximate)

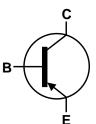
Applications

- MOSFET Gate Driving
- DC-DC Converters
- Charging circuit
- Power switches

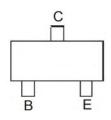
SOT23



Top View



Device Symbol



Top View Pin-Out

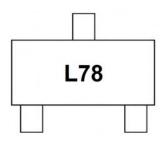
Ordering Information (Note 3)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|------------|---------|--------------------|-----------------|-------------------|
| FMMTL718TA | L78 | 7 | 8 | 3,000 |

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com
- 3. For Packaging Details, go to our website at http://www.diodes.com.

Marking Information



L78 = Product Type Marking Code

FMMTL718
Document Number: DS33132 Rev. 2 - 2



Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | -20 | V |
| Collector-Emitter Voltage | V _{CEO} | -20 | V |
| Emitter-Base Voltage | V_{EBO} | -5 | V |
| Continuous Collector Current | Ic | -1 | Α |
| Peak Pulse Current | I _{CM} | -2 | Α |
| Base Current | I _B | -200 | mA |

Thermal Characteristics @TA = 25°C unless otherwise specified

| Characteristic | | Symbol | Value | Unit |
|---|----------|------------------|-------------|------|
| Power Dissipation | (Note 4) | P _D | 500 | mW |
| Thermal Resistance, Junction to Ambient | (Note 4) | $R_{\theta JA}$ | 250 | °C/W |
| Thermal Resistance, Junction to Lead | (Note 5) | $R_{\theta JL}$ | 197 | °C/W |
| Operating and Storage Temperature Range | | $T_{J_i}T_{STG}$ | -55 to +150 | °C |

Notes: 4. For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

5. Thermal resistance from junction to solder-point (at the end of the collector lead).

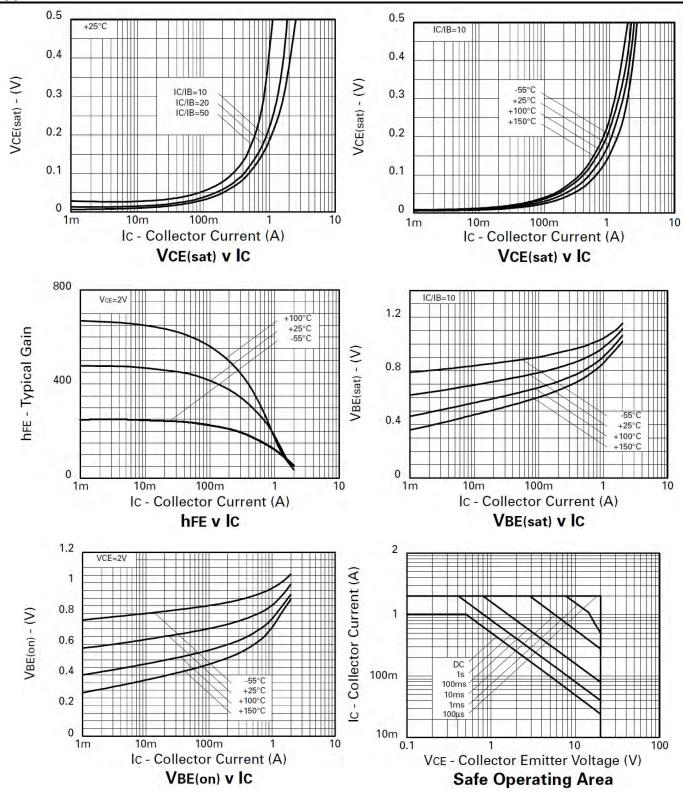
Electrical Characteristics @TA = 25°C unless otherwise specified

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|----------------------|--------------------------------|--------------------------------|-----------------------------|----------------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | -20 | -65 | | V | I _C = -100 μA |
| Collector-Emitter Breakdown Voltage (Note 6) | BV _{CEO} | -20 | -55 | | V | I _C = -10 mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -5 | -8.8 | | V | I _E = -100 μA |
| Collector Cutoff Current | I _{CBO} | | | -10 | nA | V _{CB} = -15V |
| Emitter Cutoff Current | I _{EBO} | | | -10 | nA | $V_{EB} = -4V$ |
| Collector Emitter Cutoff Current | I _{CES} | | | -10 | nA | V _{CE} = -15V |
| Static Forward Current Transfer Ratio (Note 6) | h _{FE} | 300 300 200 120 50 | 500 450 320 200 80 | | | $\begin{split} I_C &= -10 \text{mA}, \ V_{CE} = -2 \text{V} \\ I_C &= -100 \text{mA}, \ V_{CE} = -2 \text{V} \\ I_C &= -0.5 \text{A}, \ V_{CE} = -2 \text{V} \\ I_C &= -1 \text{A}, \ V_{CE} = -2 \text{V} \\ I_C &= -1.5 \text{A}, \ V_{CE} = -2 \text{V} \end{split}$ |
| Collector-Emitter Saturation Voltage (Note 6) | VCE(sat) | | -33 -130 -230 -315 | -50 -180 -320 -450 | mV mV mV | I_C =- 100mA, I_B = -10mA I_C =- 500mA, I_B = -20mA I_C = -1A, I_B = -50mA I_C = -1.5A, I_B = -100mA |
| Base-Emitter Turn-On Voltage(Note 6) | V _{BE(on)} | | -0.85 | -1.0 | V | I _C = -1.25A, V _{CE} = -2V |
| Base-Emitter Saturation Voltage(Note 6) | V _{BE(sat)} | | -0.95 | -1.1 | V | $I_C = -1.25A$, $I_B = -100mA$ |
| Equivalent On-Resistance | R _{CE(sat)} | | 210 | | mΩ | I _C = -1.5A |
| Output Capacitance | C _{obo} | | 9 | 12 | pF | V _{CB} = -10V, f = 1MHz |
| Transition Frequency | f _T | | 265 | | MHz | $V_{CE} = -10V, I_{C} = -50mA,$ f = 100MHz |
| Turn-On Time | t _{on} | | 108 | | ns | V _{CC} =-10V, I _C =-1A |
| Turn-Off Time | t _{off} | | 121 | | ns | $I_{B1} = I_{B2} = -10$ mA |

Note: 6. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%

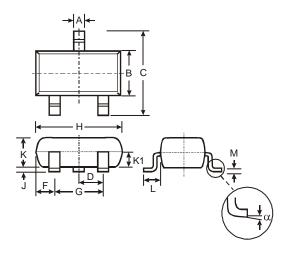


Typical Electrical Characteristics



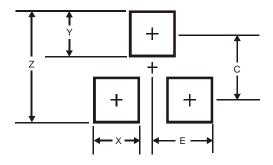


Package Outline Dimensions



| | SOT23 | | | | | |
|------------|----------------------|------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.37 | 0.51 | 0.40 | | | |
| В | 1.20 | 1.40 | 1.30 | | | |
| С | 2.30 | 2.50 | 2.40 | | | |
| D | 0.89 | 1.03 | 0.915 | | | |
| F | 0.45 | 0.60 | 0.535 | | | |
| G | 1.78 | 2.05 | 1.83 | | | |
| Н | 2.80 | 3.00 | 2.90 | | | |
| J | 0.013 | 0.10 | 0.05 | | | |
| K | 0.903 | 1.10 | 1.00 | | | |
| K 1 | - | 1 | 0.400 | | | |
| L | 0.45 | 0.61 | 0.55 | | | |
| M | 0.085 | 0.18 | 0.11 | | | |
| α | 0° | 8° | - | | | |
| All | All Dimensions in mm | | | | | |

Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| Х | 0.8 |
| Y | 0.9 |
| С | 2.0 |
| Е | 1.35 |





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